

# N-CHANNEL MOS FIELD EFFECT POWER TRANSISTOR

## 2SK774

**DESCRIPTION** The 2SK774 is N-channel MOS Field Effect Power Transistor designed for switching power supplies DC-DC converter.

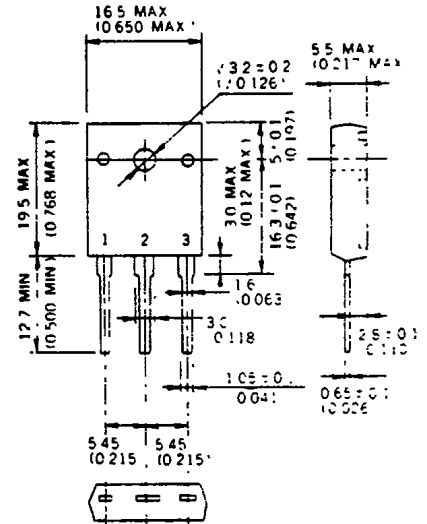
- FEATURES**
- Suitable for switching power supplies, actuator controls, and pulse circuits
  - Low  $R_{DS(on)}$
  - No second breakdown

**ABSOLUTE MAXIMUM RATINGS**

Maximum Temperatures	
Storage Temperature	-55 to +150 °C
Channel Temperature	150 °C Maximum
Maximum Power Dissipation ( $T_C = 25\text{ °C}$ )	
Total Power Dissipation	120 W
Maximum Voltages and Currents ( $T_A = 25\text{ °C}$ )	
$V_{DSS}$ Drain to Source Voltage	500 V
$V_{GSS}$ Gate to Source Voltage	±20 V
$I_{D(DC)}$ Drain Current (DC)	±18 A
$I_{D(pulse)}$ Drain Current (pulse)*	±60 A

\*  $PW \leq 300\ \mu s$ , Duty Cycle  $\leq 2\%$

**PACKAGE DIMENSIONS**  
in millimeters (inches)

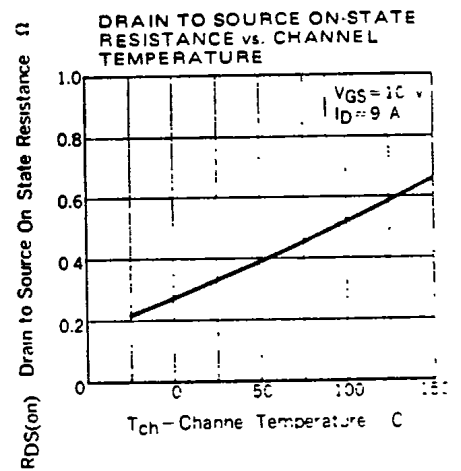
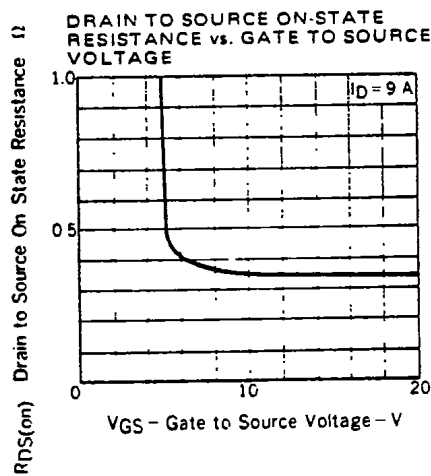
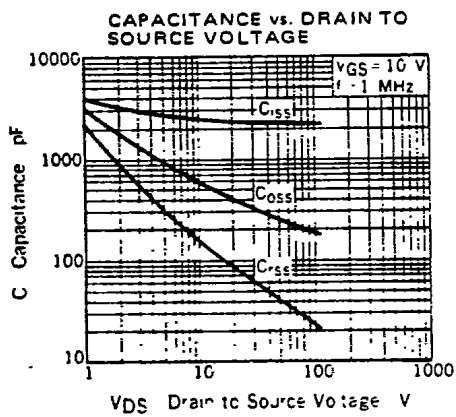
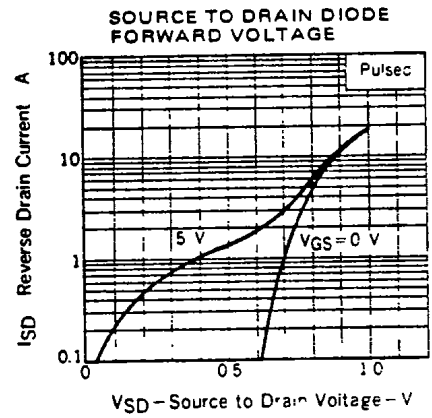
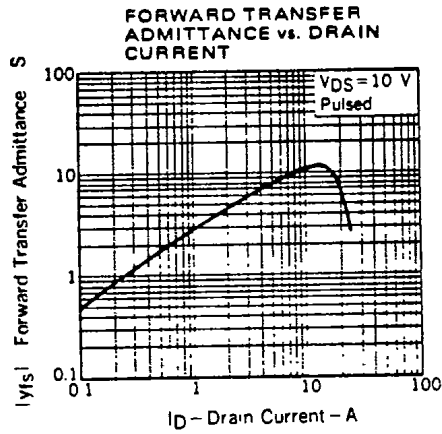
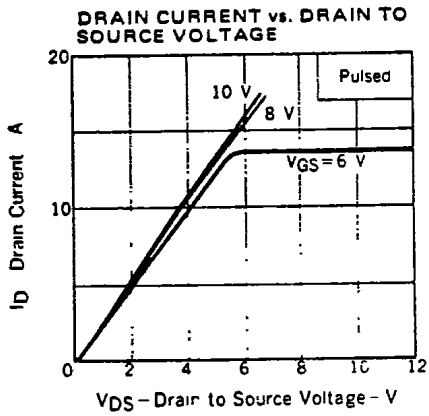
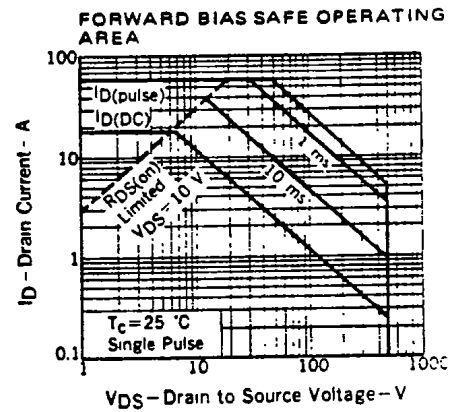
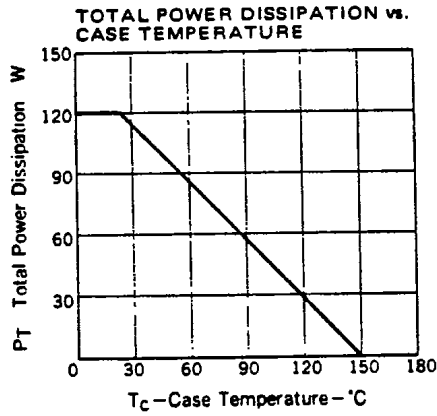
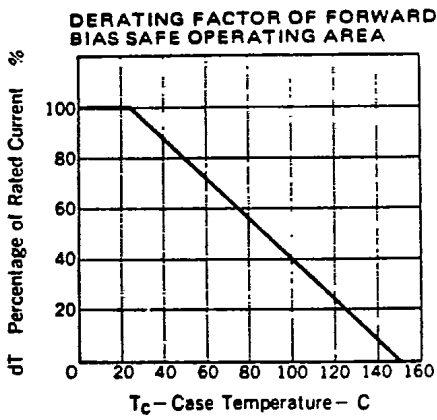


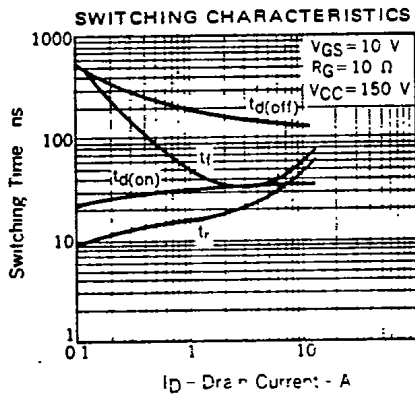
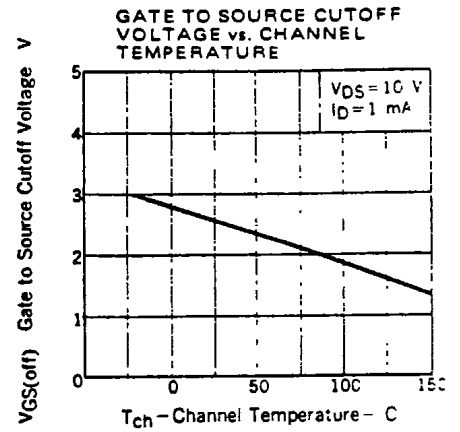
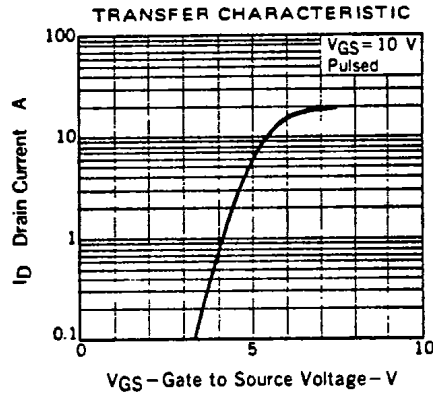
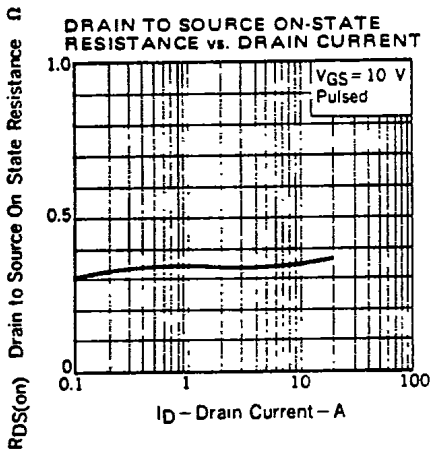
1. Gate
2. Drain (Fin)
3. Source

**ELECTRICAL CHARACTERISTICS ( $T_A = 25\text{ °C}$ )**

SYMBOL	CHARACTERISTIC	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
$I_{DSS}$	Drain Leakage Current			100	$\mu A$	$V_{DS} = 500\text{ V}$ , $V_{GS} = 0$
$I_{GSS}$	Gate to Source Leakage Current			±100	nA	$V_{GS} = \pm 20\text{ V}$ , $V_{DS} = 0$
$V_{GS(off)}$	Gate to Source Cutoff Voltage	1.5		3.5	V	$V_{DS} = 10\text{ V}$ , $I_D = 1\text{ mA}$
$ Y_{fs} $	Forward Transfer Admittance	8.0			S	$V_{DS} = 10\text{ V}$ , $I_D = 9\text{ A}$
$R_{DS(on)}$	Drain to Source On-State Resistance		0.35	0.45	$\Omega$	$V_{GS} = 10\text{ V}$ , $I_D = 9\text{ A}$
$C_{iss}$	Input Capacitance		2600		pF	
$C_{oss}$	Output Capacitance		620		pF	$V_{DS} = 10\text{ V}$ , $V_{GS} = 0$ , $f = 1\text{ MHz}$
$C_{rss}$	Reverse Transfer Capacitance		170		pF	
$t_{d(on)}$	Turn-On Delay Time		35		ns	$I_D = 9\text{ A}$ , $V_{CC} = 150\text{ V}$
$t_r$	Rise Time		55		ns	$V_{GS(on)} = 10\text{ V}$
$t_{d(off)}$	Turn-Off Delay Time		150		ns	$R_L = 16\ \Omega$
$t_f$	Fall Time		55		ns	$R_{in} = 10\ \Omega$

# TYPICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )





### SWITCHING TIME TEST CIRCUIT

